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Giant Hysteresis of Single-Molecule Magnets Adsorbed on a Nonmagnetic Insulator

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Single-molecule magnets (SMMs)^[1] are very promising for molecular spintronics^[2] and quantum information processing,^[3] because of their magnetic bistability and the quantum nature of their spin. The first step toward devices based on SMMs is their adsorption onto electrode surfaces.^[4,5] However, this step already represents a serious obstacle as it severely compromises the magnetic remanence.^[6–13] Here, we solve this problem by introducing a tunnel barrier between the SMMs and the metal electrode. For TbPc₂ SMMs^[14,15] on nonmagnetic, insulating MgO on Ag(100) we demonstrate record values of the magnetic remanence and the hysteresis opening, outperforming any previously reported surface adsorbed SMMs.

The two key properties of a magnet relevant to devices are large remanence and wide hysteresis opening. Achieving these goals represents a largely unresolved challenge for SMMs adsorbed at surfaces. Current strategies are to exploit weak adsorption, e.g., on graphite,^[8,9] or decoupling from the surface by long chemical linkers^[4,5,10] or bulky ligands.^[11,12] While some of the approaches were successful in achieving a sizeable butterfly-like hysteresis opening,^[4,5,10–12] so far all attempts to enhance the vanishingly small magnetic remanence of SMMs in contact with surfaces have failed.^[4–13] Consequently, the magnetic remanence of surface-adsorbed SMMs lags far behind the benchmark set by bulk samples,^[16] which are, however, not useful for device applications.

Here we introduce an entirely different strategy, namely, the insertion of a tunnel barrier between the SMMs and the

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metal electrode. We use nonmagnetic, insulating MgO, wellknown in inorganic spintronic applications,^[17,18] which allows to control the electron tunneling rate over many orders of magnitude.^[19] Moreover, we employ the TbPc₂ SMM^[14,15,20-23] as a model system. In the neutral molecule, the Tb(III) ion exhibits an electronic spin state of I = 6. It is sandwiched between two phthalocyanine (Pc) macrocycles (cf. schematic view in Figure 1a) hosting an unpaired electron delocalized over the Pc ligands. The easy-axis-type magnetic anisotropy imposes an energy barrier of ≈65 meV for magnetization reversal,^[23] which is largest within the whole series of lanthanide-Pc₂ SMMs.^[14,15] On nonmagnetic conducting substrates, only vanishing remanence^[6-10] and very narrow hysteresis loops^[6-9] were observed, much smaller than in bulk measurements,^[20] illustrating the disruptive effects of the surface. We note that the adsorption of TbPc2 on (anti)ferromagnetic materials represents a different situation because of the magnetic exchange interaction with the substrate.^[24,25] In those cases, the SMMs were not shown to exhibit slow relaxation of magnetization. Rather, the hysteresis is linked to the one of the magnetic substrates, i.e., it is not an intrinsic property of the SMMs. Overall, the detailed knowledge on TbPc₂ makes it an ideal candidate to test if a tunnel barrier can boost the magnetic properties of surface-adsorbed SMMs. In this communication we show that the magnetic remanence and hysteresis opening obtained with TbPc2 on MgO tunnel barriers outperform the ones of any other surface-adsorbed SMM^[4-13,26] as well as those of bulk samples of TbPc₂.^[20]

The scanning tunneling microscopy (STM) images in Figure 1b,c show that TbPc₂ self-assembles by forming perfectly ordered 2D islands on two monolayers (MLs) of MgO on Ag(100). In line with former results, the SMMs are adsorbed flat on the surface (cf. discussion of our STM and X-ray linear dichroism (XLD) data below).^[6,27] This excludes that the extraordinary magnetic properties observed in this study are due to upstanding molecules having their macrocycles perpendicular to the surface, which would lead to a reduced interaction of the Tb(III) ion with the surface. The high-resolution image in Figure 1c reveals eight lobes per molecule, reminiscent of the staggered conformation of the two phthalocyanine ligands.^[27] Islands with the identical molecular assembly are formed by TbPc₂ adsorbed directly onto Ag(100), as shown in the Supporting Information.

The magnetic properties of the Tb(III) ions in the surfaceadsorbed SMMs are determined by X-ray magnetic circular dichroism (XMCD) measurements at the $M_{4,5}$ ($3d \rightarrow 4f$) edges of Tb. For sub-MLs of TbPc₂ on MgO we find a strong remanence larger than 40% of the saturation magnetization M_{sat} and



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Figure 1. Self-assembly and exceptional magnetic remanence and hysteresis of TbPc₂ molecules on insulating MgO films. a) Sketch of a TbPc₂ molecule on an ultrathin MgO film on Ag(100). b,c) Scanning tunneling microscopy images revealing self-assembled arrays of TbPc₂ on two monolayers (MLs) of MgO. The image sizes and parameters (scale bar, bias voltage, and current setpoint) are (10 nm, +2 V, 20 pA) for (b) and (1 nm, -2 V, 20 pA) for (c), respectively. d,e) Hysteresis loops obtained with XMCD at 3 K for 0.6 ML TbPc₂ on 5 ML MgO compared with 0.3 ML TbPc₂ adsorbed directly on Ag(100) and with a TbPc₂ multilayer (3 ML) on MgO (field sweep rate 2 T min⁻¹, normal incidence, X-ray flux (d) 0.25 Φ_0 and (e) Φ_0 , respectively).

a hysteresis opening up to 3 T at 3 K (Figure 1d). These values vastly exceed the corresponding records reported for any surface-adsorbed SMM^[4–13,26] as well as the ones reported for bulk TbPc₂.^[20] The large remanence indicates that quantum tunneling of magnetization is strongly suppressed for fields below 3 T, with only a very subtle modulation of the relaxation rate across the hysteresis loop.

The effect of the tunnel barrier becomes evident when comparing with TbPc_2 directly adsorbed onto Ag(100) where the hysteresis opening is barely visible. In fact, the area of the opening has decreased by a factor of 10 (Figure 1e). The large opening of sub-MLs on MgO/Ag(100) is also reduced in TbPc₂ multilayers (Figure 1e). This is attributed to magnetic interactions between the molecules.^[21] In addition to MgO, we also investigated hexagonal boron nitride $(h-BN)^{[28]}$ as a tunnel barrier. The hysteresis opening on *h*-BN is wider than the one reported for most surface-adsorbed TbPc₂ (Supporting Information), however, it is significantly narrower than on the MgO thin film. MgO is more efficient in suppressing electron scattering from the substrate as it can be grown in multilayers, while *h*-BN forms a self-limiting monolayer.

The electronic ground state and magnetic moments of the Tb ion as well as the molecular orientation are inferred from the X-ray absorption spectra (XAS) and their circular (XMCD) and linear (XLD) dichroism (Figure 2). XLD, which is directly sensitive to the molecular orientation, evidences that the molecules adsorb with the same orientation on MgO (Figure 2) and on Ag(100) (Supporting Information). This is in line with our STM results (Figure 1b,c and Figures S1-S3, Supporting Information) showing that the TbPc2 macrocycles are parallel to the surfaces of MgO and Ag(100). Furthermore, our results are consistent with XLD spectra of TbPc2 on metal surfaces reported in the literature.^[6,7] The same orientation is also observed for TbPc2 on h-BN and for the multilayer (Supporting Information). The Tb spin and orbital magnetic moments extracted from the XMCD spectra (cf. Supporting Information) are in excellent agreement with previous studies of TbPc2 on metal surfaces^[6,7] and on graphite.^[8,9] Therefore the larger remanence is neither due to a different magnetic ground state of the Tb ion nor to strong modifications in the magnetic anisotropy.

To determine the magnetic relaxation times of $TbPc_2/MgO$, we have performed time-dependent XMCD measurements at 0.5 T after saturating the magnetization at 4 T (Figure 3).

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Figure 2. X-ray spectra of a submonolayer of TbPc₂ on MgO revealing the magnetic anisotropy and the orientation of the molecules. X-ray absorption spectra (XAS) at the Tb M_{4,5} edges acquired at 3 K using circularly (σ^{+},σ^{-}) and linearly (σ^{h},σ^{v}) polarized light. The same arbitrary units are used in (a) and (b). a) The spectra with circularly polarized X-rays were obtained in normal ($\theta = 0^{\circ}$) and grazing ($\theta = 60^{\circ}$) incidence in an applied magnetic field of 6.8 T. b) Their difference, XMCD, is a direct measure of the magnetic moment of Tb. The peak XMCD-to-XAS ratio ($\sigma^{+} - \sigma^{-}$)/($\sigma^{+} + \sigma^{-}$) is -80% and -55% for normal and grazing incidence, with the strongest XLD-to-XAS ratio of -45%.

The magnetization versus time traces M(t) decay exponentially (Figure 3a). This decay with rate τ^{-1} becomes faster with increasing X-ray flux. Therefore, intrinsic relaxation



Figure 3. Intrinsic relaxation and X-ray induced demagnetization. The time-dependent XMCD signal was obtained at 0.5 T after magnetizing the samples at 4 T and switching on the X-ray beam at time t = 0, immediately after reaching 0.5 T. a) With increasing X-ray flux Φ , the magnetization *M* decays faster. The exponential fits yield the decay times τ of the magnetization as a function of X-ray flux Φ . b) The intercept yields the intrinsic relaxation time $\tau_i = 14^{+0}_{-4}$ min.

(rate τ_i^{-1}) and photon-induced demagnetization (rate τ_{ph}^{-1})^[29] coexist. The respective rates add up yielding the decay rate $\tau^{-1} = \tau_i^{-1} + \tau_{ph}^{-1}$. Consistently, the fit $\tau(\Phi)^{-1} = \tau_i^{-1} + \sigma\Phi$ in Figure 3b shows that the decay rates are linear with the X-ray flux Φ within the error bars. The intercept at zero X-ray flux yields the intrinsic relaxation time $\tau_i = 14^{+10}_{-4}$ min at 0.5 T, and the slope $\sigma = 0.21 \pm 0.05$ nm² = $(2.1 \pm 0.5) \times 10^9$ barn is the cross section of the photon-induced demagnetization process. The asymptotic values of the magnetization decrease with increasing X-ray flux Φ , indicating that the X-ray-induced demagnetization drives the magnetization to a value which is lower than the thermodynamic equilibrium at 0.5 T, in contrast to the intrinsic relaxation. Notably, the demagnetization is not a result of simple spatially homogeneous heating or radiation damage (cf. Supporting Information).

Temperature-dependent hysteresis loops of TbPc₂/MgO (**Figure 4**) evidence slow relaxation of the magnetization beyond 6 K. In fact, the hysteresis area still exhibits a finite value at 8 K, which is the highest blocking temperature ever reported for surface-adsorbed SMMs.

We rationalize the large magnetic remanence and the wide hysteresis opening of TbPc₂ on MgO by identifying two key aspects. These are, first, the strong suppression of scattering of conduction electrons from the metal at the molecule and, second, the low molecule-surface hybridization. The electron tunneling rate depends exponentially on the barrier thickness. For MgO tunnel barriers it is reduced by a factor of $\approx 3 \times 10^3$ per nanometer (≈ 5 ML MgO).^[30] In accordance, narrower hysteresis loops are observed for thinner MgO and for *h*-BN monolayers (cf. Supporting Information). This suggests that for thicker MgO films or bulk MgO the remanence and the hysteresis opening will be equal to or larger than the ones observed in the present study.

Regarding the second key aspect, bulk studies have shown that the preservation of the ideal D_{4d} symmetry is important to achieve long relaxation times and large coercive fields in TbPc₂.^[21,22] Symmetry breaking enables mixing terms in the TbPc₂ spin Hamiltonian that, together with the hyperfine interaction, promotes quantum tunneling of magnetization especially around zero field.^[4,5,21,22] Owing to the low hybridization on MgO the upper and lower Pc ligands retain the same electronic structure as in the gas phase, preserving the molecular

> D_{4d} symmetry nearly perfectly. By contrast, upon direct adsorption onto metal surfaces the electronic structure of the lower Pc ligand in contact with the surface is slightly altered because of adsorption bonds and molecule-surface charge transfer, reducing the symmetry of the Tb ligand field to C_{4v} or lower. Thus, symmetry breaking of the ligand field, presumably together with electron scattering, leads to the barely open hysteresis loops of TbPc₂ on Ag(100) in this work and on Au(111),^[7] and to the closed loop on Cu(100).^[6] Graphite is weakly hybridizing, however, it does not suppress electron scattering leading to narrow hysteresis openings as well.^[8,9]







Figure 4. Temperature-dependent magnetization curves of TbPc₂/MgO/Ag(100). With increasing temperature the magnetization loop gradually closes until the hysteresis fully vanishes at 10 K (X-ray flux Φ_0 , 0.3 ML TbPc₂ on 4.8 ML MgO). The area of the hysteresis opening is plotted in the inset.

Concerning magnetic interactions between adjacent molecules for submonolayers of TbPc_2 , we observe a negligible influence of the molecular coverage on the hysteresis opening (Supporting Information). Together with the 2D molecular selfassembly seen by STM, this implies that lateral magnetic interactions are insignificant. On the contrary, our data on TbPc_2 multilayers on MgO reveal that vertical interactions accelerate magnetization relaxation.^[20,21]

In summary, we have demonstrated that MgO thin films realize the combination of efficient protection from electron scattering and weak molecule–surface hybridization to achieve optimal properties of SMMs on electrode surfaces. In addition, in the present case of $TbPc_2$ the molecules are self-assembled into well-ordered islands leading to highly uniform molecular ensembles with out-of-plane easy axes. Epitaxial MgO layers promote a very large tunnel magnetoresistance in inorganic devices based on ferromagnetic electrodes.^[31] Therefore, the combination of SMMs and epitaxial MgO tunnel junctions opens up a path toward SMM-based tunnel devices.

Experimental Section

Sample Preparation: The Ag(100) single crystal substrate was prepared by repeated cycles of sputtering with Ar⁺ ions and annealing. The epitaxial MgO layers were grown by sublimation of Mg in O₂ atmosphere (10⁻⁶ mbar) while keeping the sample at 625 K.^[19] A submonolayer of TbPc₂ was sublimed at 650 K at a rate of ≈0.1 ML min⁻¹ onto the surface kept at room temperature. The multilayer sample was prepared by sublimation of ≈3 ML of TbPc₂ onto MgO/Ag(100).

X-Ray Absorption Spectroscopy: The X-ray absorption experiments were performed at the EPFL/PSI X-Treme beamline^[32] at the Swiss Light Source at a temperature of 3 K in total electron yield mode using circularly (σ^+ , σ^-) and linearly polarized (σ^h , σ^\prime) X-rays with the magnetic field applied parallel to the X-ray beam. XMCD and XLD spectra correspond to the differences, ($\sigma^+ - \sigma^-$) and ($\sigma^v - \sigma^h$), respectively. The

Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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